

TECHNOLOGY DATA SHEET & SPECIFICATIONS

MODEL: <u>5013M1D</u>

Features

'Fast response time

'High photo sensitivity

'Small junction capacitance

Pb free



Descriptions

5013M1C is a high speed and high sensitive PIN photodiode in a standard 5Φplastic package.

The device is sensitive to visible and infrared radiation.

Applications

□ Automatic door sensor
□Camera
□Game machine
☐ High speed photo detector



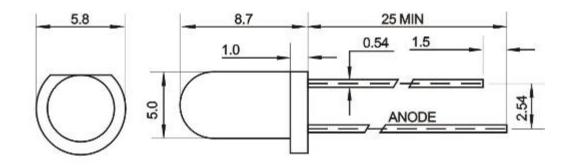
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Device Selection Guide

LED Part No.	Chip	Lama Calan
	Material	Lens Color
5013M1D	Silicon	Black

Package Dimensions



UNIT:mm

Notes:

- 1.All dimensions are in millimeters
- 2.Tolerances unless dimensions ±0.1mm



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Electro-Optical Characteristics (Ta=25□)

Parameter	Symbol	Min.	TYP.	Max.	Unit	Condition
Rang Of Spectral Bandwidth	λ	840		1100	nm	
Wavelength of Peak Sensitivity	λР		940		nm	
Collector-Emitter Breakdown Voltage	VBR CEO	30			V	IC=100µA IB=0
Emitter-Collector Breakdown Voltage	VBR ECO	5			V	IE=100μA IB=0
Collector-Emitter Saturation Voltage	VCE (SAT)			0.4	V	IC=0.1mA H=2.5mW/c m²
Collector Dark Current	ID			100	nA	VCE=10V H=0mW/c m²
Rise Time (10% to 90%)	TR		15		μs	VCE=5V IC=1mA
Fall Time (90% to 10%)	TF		15		μs	RL=100Ω
On State Collector Current	I(ON)		4		mA	VCE=5V Ee=1mW/c m² λ=940nm
View Angle	201/2		45		deg	IF=20mA λ=940nm

Note:

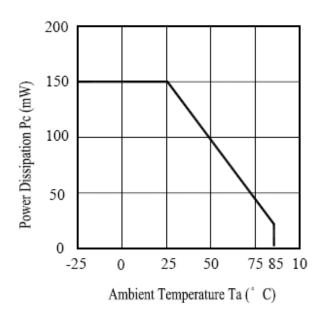
- 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.
- 2. θ 1/2 is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

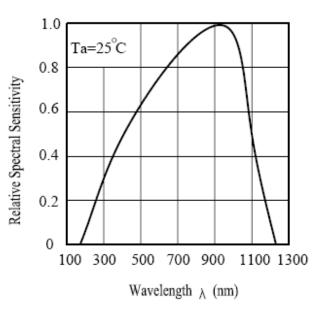


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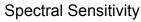
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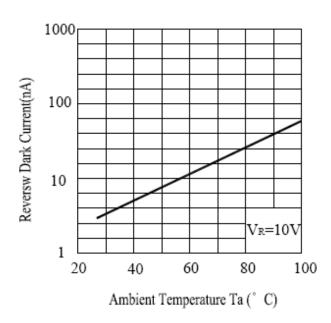
Typical Electro-Optical Characteristics Curves

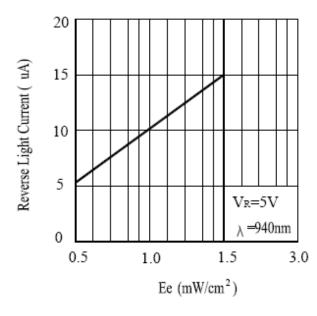




Power Dissipation vs Ambient Temperature







Dark Current vs Ambient Temperature

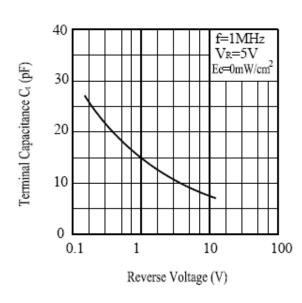
Reverse Light Current vs. Ee

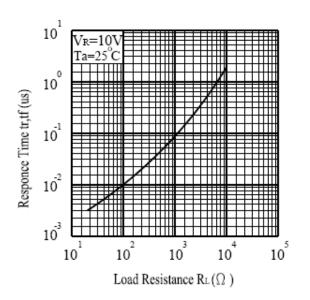


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Typical Electro-Optical Characteristics Curves





Terminal Capacitance vs. Reverse Voltage

Response Time vs. Load Resistance

Notes

- 1. Above specification may be changed without notice. HYLED will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. HYLED assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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